# Contents


## Letters

Induced crystallization of amorphous silicon film in contact with aluminum ..... 1
W. Cai and D. Wan (Sichuan, China)

Plasma-assisted chemical vapour deposition of diamond by hollow cathode arc discharge ..... 4
J. Stiegler, K. Roth, K. Hammer and W. Scharff (Chemnitz, Germany)

## Synthesis and Characterization

Characterization of $TiO_2$ films modified by platinum doping ..... 7
L. Avalle, E. Santos, E. Leiva and V. A. Macagno (Cordoba, Argentina)

Effect of solvent on properties of sol–gel-derived $TiO_2$ coating films ..... 18
L. Hu, T. Yoko, H. Kozuka and S. Sakka (Kyoto-Fu, Japan)

Evaluation of tetra-alkylchromium precursors for organometallic chemical vapor deposition. II: Unusual low temperature chromium carbide deposition from $Cr[C(CH_3)_3]_4$ ..... 24
F. Maury (Toulouse, France) and F. Ossola (Padova, Italy)

Effect of substrate on growth of $WS_2$ thin films ..... 30
M. Genut, L. Margulis, R. Tenne and G. Hodes (Rehovot, Israel)

Thermodynamic aspects of pyrite film formation by sulphur conversion of iron ..... 37
G. Pimenta and W. Kautek (Berlin-Dahlem, Germany)

Serial cosputtering of mixed Al/Zr and $Al_2O_3/ZrO_2$ films ..... 46
A. Belkind (Murray Hill, NJ, USA), R. Laird (Concord, CA, USA), Z. Orban and P. White Rafalko (Murray Hill, NJ, USA)

Anisotropic grain growth of $\delta$-NiMo compound by exothermic solid state diffusional intermixing ..... 52
T. C. Chou and T. G. Nieh (Palo Alto, CA, USA)

X-Ray characterization of Au/Ni multilayer thin films ..... 63
J. Chaudhuri, S. M. Alyan (Wichita, KS, USA) and A. F. Jankowski (Livermore, CA, USA)

Growth and characterization of Nb/Gd multilayers for different substrate temperatures ..... 69
C. Surgers and H. v. Löhneysen (Karlsruhe, Germany)

Hillock growth on aluminum and aluminum alloy films ..... 80
S. Aceto, C. Y. Chang and R. W. Vook (Syracuse, NY, USA)

## Surfaces, Interfaces and Colloidal Behaviour

Diffusion parameters for oxygen and gadolinium at gadolinium–metal interfaces ..... 87
D. Raiser, C. Speisser and J. C. Sens (Strasbourg, France)

## Metallurgical, Protective and Hard Layers

Determination of elastic modulus and thickness of surface layers by ultrasonic surface waves ..... 92
D. Schneider, T. Schwarz and B. Schultrich (Dresden, Germany)

Kinetics of chemical vapor deposition of tungsten carbide ..... 103
C. M. Kelly (Villanova, PA, USA), D. Garg and P. N. Dyer (Allenstown, PA, USA)

Diamond-like amorphous carbon films prepared by r.f. sputtering in argon: electron-assisted investigations ..... 109
J. Ullmann, S. Schulze, J. Erben, W. Grünewald (Chemnitz, Germany), D. Heger (Freiberg, Germany) and I. Mühling (Chemnitz, Germany)

Influence of selected process parameters on the deposition of polymer-like amorphous hydrogenated carbon films in glow discharges . 119
T. Danzer, G. Marx and G. Riedel (Chemnitz, Germany)

An investigation of the microfrictional behavior of $C_{60}$ particle layers on aluminum ..... 129
P. J. Blau and C. E. Haberlin (Oak Ridge, TN, USA)

## Mechanics and Nanomechanics of Thin Layers

Internal stress, thermal expansion coefficient and bi-elastic modulus of photochemically vapour deposited hydrogenated amorphous silicon films ..... 135
S. Guo and W. Wang (Shanghai, China)

On the chemical and mechanical properties of sputtered silicon nitride films ..... 139
F. Jansen, A. Day (Murray Hill, NJ, USA) and L. Wamboldt (Concord, CA, USA)

## Electronics, Optics and Opto-electronics

Formation and dissolution behaviour of $ZrO_2$ film in $H_3PO_4$ acid solutions ..... 146
A. S. Mogoda, F. El-Taib Heakal and A. A. Ghoneim (Giza, Egypt)

Photoluminescence and Raman studies of CdS films grown by metal–organic chemical vapor deposition on Si{111} substrates ..... 153
A. K. Berry (Fairfax, VA, USA), P. M. Amirtharaj (Fort Belvoir, VA, USA), J. T. Du (Fairfax, VA, USA), J. L. Boone and D. D. Martin (Rolla, MO, USA)

Optical properties of selective reflection $TiN_x$ films ..... 157
K. Antonova, G. Grigorov, I. Martev (Sofia, Bulgaria), V. Yakovlev and G. Zhizhin (Moscow, Russia)

Excimer laser ablated deposition of ferroelectric lead germanate thin films ..... 162
C. J. Peng and S. B. Krupanidhi (Pennsylvania, PA, USA)

The effects of mercury UV photolysis on vapour deposition of $SnO_2$ ..... 170
C. H. Lee and S. H. Liu (Tainan, Taiwan)

A.c. impedance investigation of $Ta_2O_5$ film for use as a storage capacitor dielectric ..... 176
A. Rešetić and M. Metikoš-Huković (Zagreb, Croatia)

Microstructure of polycrystalline $CuInSe_2$/Cd(Zn)S heterojunction solar cells ..... 183
J. S. Chen, E. Kolawa, C. M. Garland, M. A. Nicolet and R. P. Ruiz (Pasadena, CA, USA)

An "all-gel" electrochromic device ..... 193
N. Ozer, F. Tepehan and N. Bozkurt (Istanbul, Turkey)

Optical properties of evaporated small silver particles ..... 199
M. H. Lee, P. J. Dobson and B. Cantor (Oxford, UK)

Structural and electrical properties of ion beam sputter deposited tantalum films ..... 206
F. Sajovec, P. M. Meuffels and T. Schober (Jülich, Germany)

## Langmuir–Blodgett, Biological and Related Films

Surface plasmon resonance as a probe of the complexing process of valinomycin Langmuir–Blodgett films by potassium ions ..... 210
X. L. Yang, P. Dutta, G. K. Wong and J. B. Ketterson (Evanston, IL, USA)

Langmuir–Blodgett mono- and multilayers of fluorocarbon amphiphilic polymers and their application in photogalvanic metal–insulator–semiconductor structures ..... 215
D. A. Znamersky (Moscow, Russia), R. G. Yusupov (Yaroslavl, Russia) and B. V. Mislavsky (Moscow, Russia)

Second harmonic generation in hemicyanine Langmuir–Blodgett monolayers deposited from aqueous subphase of halide salt solution 221
X. Liu, L. Liu, Z. Chen, X. Lu, J. Zheng and W. Wang (Shanghai, China)

Photo-induced regulation of nematic liquid crystal alignment by mixed monolayers of an azobenzene with long chain alkyl residues.. 226
K. Aoki (Hiroshima, Japan), Y. Kawanishi, T. Seki, T. Tamaki, M. Sakuragi (Ibaraki, Japan) and K. Ichimura (Yokohama, Japan)

Epitaxial growth of long chain esters prepared by physical vapour deposition ..... 231
K. Yase (Tsukuba, Japan), M. Sano (Kobe, Japan) and S. Ogihara (Kanagawa, Japan)

Fabrication of organic–inorganic pseudosuperlattice ..... 236
K. Orihara (Yonezawa, Japan)

## Thin Film Devices, Sensors and Actuators

A method for the determination of the thermal transport properties of submicron-thick dielectric films with the use of an analytical expression ..... 239
S. Ohkubo and M. Okuda (Kanagawa, Japan)

Interaction of $NO_2$ with copper phthalocyanine thin films. I: Characterization of the copper phthalocyanine films ..... 244
S. Dogo, J. P. Germain, C. Maleysson and A. Pauly (Aubière, France)

Interaction of $NO_2$ with copper phthalocyanine thin films. II: Application to gas sensing ..... 251
S. Dogo, J.-P. Germain, C. Maleysson and A. Pauly (Aubière, France)

Effects of substrate temperature, deposition pressure, and thickness on the morphology of ultrathin platinum film on $SiO_2$/Si substrate 257
R. N. Esfahani, G. J. Maclay (Chicago, IL, USA) and G. W. Zajac (Naperville, IL, USA)

## Condensed Matter Film Behaviour

Energy considerations for preparing thin films by ion beam deposition ..... 266
A. Jain (Bombay, India)

Monte Carlo simulation of high rate reactive sputtering of tin oxide in planar d.c. magnetron systems ..... 270
C. D. Tsiogas and J. N. Avaritsiotis (Athens, Greece)

**Author Index** ..... 278

**Subject Index** ..... 279